

Unit in mm

Telecommunication

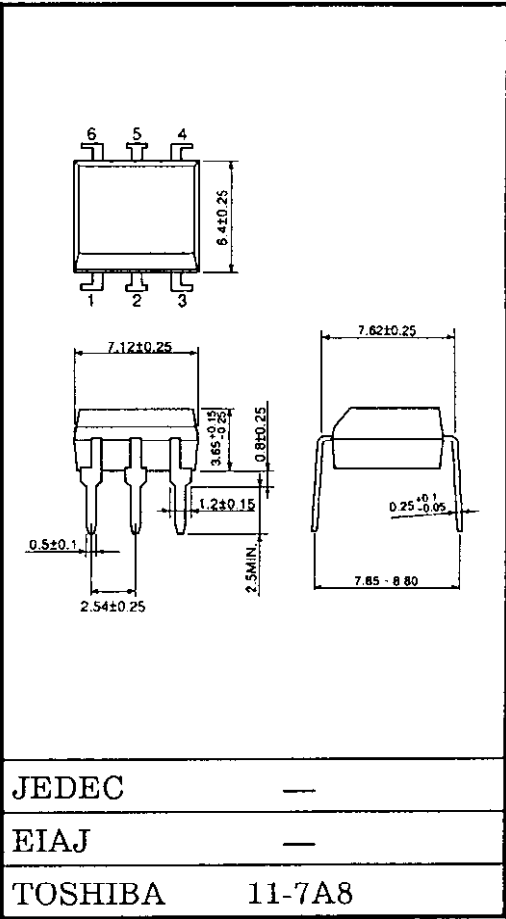
Data Acquisition

Measurement Instrumentation

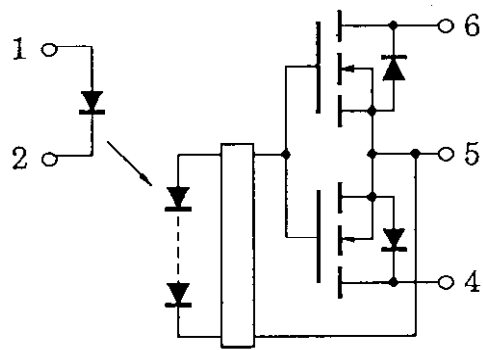
The Toshiba TLP596G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a six lead plastic DIP package. The TLP596G is a bi-directional switch which can replace mechanical relays in many applications.

- Peak Off-State Voltage : 400V (Min.)
- On-State Current : 120mA (Max.) (A Connection)
- On-State Resistance : 30Ω (Max.) (A Connection)
- Insulation Thickness : 0.4mm (Max.)
- Isolation Voltage : 2500Vrms (Min.)
- UL Recognized : UL1577, File No. E67349
- Trigger LED Current (Ta = 25°C)

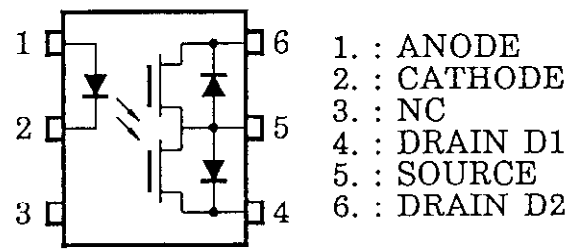
Supplementary Information	Page (s)
Lead Form Options	31-32
Tape and Reel	39-40



Pin Configuration (Top View)



Schematic



The information contained here is subject to change without notice.
The information contained herein is presented only as guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others. These TOSHIBA products are intended for usage in general electronic equipments (office equipment, communication equipment, measuring equipment, domestic electrification, etc.) Please make sure that you consult with us before you use these TOSHIBA products in equipments which require high quality and/or reliability, and in equipments which could have major impact to the welfare of human life (atomic energy control, spaceship, traffic signal, combustion control, all types of safety devices, etc.). TOSHIBA cannot accept liability to any damage which may occur in case these TOSHIBA products were used in the mentioned equipments without prior consultation with TOSHIBA.

CLASSIFICATION (Note 1)	TRIGGER LED CURRENT (mA)		MARKING OF CLASSIFICATION
	@I _{ON} = 120mA		
	MIN.	MAX.	
(IFT2)	—	2	T2
Standard	—	5	T2, Blank

Note 1: Application type name for certification test, please use standard product type name, i.e., TLP596G (IFT2): TLP596G

Maximum Ratings (Ta = 25°C)

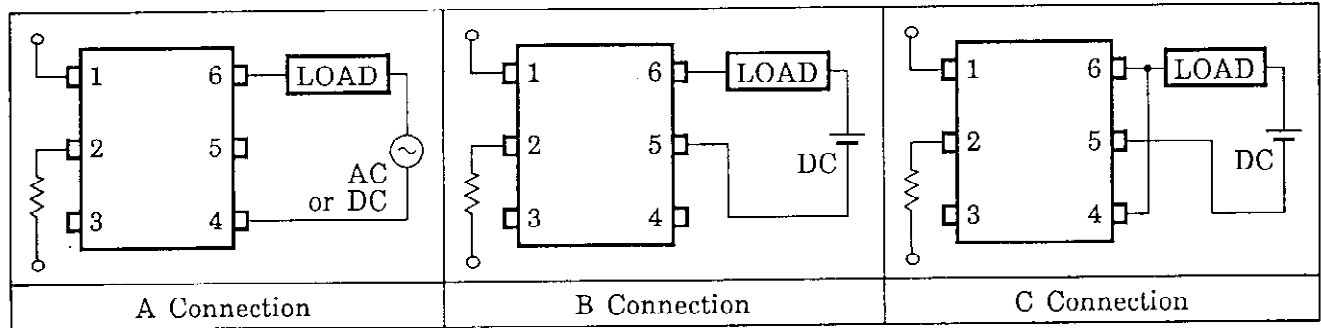
CHARACTERISTIC			SYMBOL	RATING	UNIT
LED	Forward Current		I _F	50	mA
	Forward Current Derating (Ta ≥ 25°C)		ΔI _F /°C	-0.5	mA/°C
	Peak Forward Current (100μs pulse, 100pps)		I _{FP}	1	A
	Reverse Voltage		V _R	5	V
	Junction Temperature		T _j	125	°C
DETECTOR	Off-State Output Terminal Voltage		V _{OFF}	400	V
	On-State RMS Current	A Connection	I _{ON}	120	mA
		B Connection		150	
		C Connection		200	
	On-State Current Derating (Ta ≥ 25°C)	A Connection	ΔI _{ON} /°C	-1.2	mA/°C
		B Connection		-1.5	
		C Connection		-2.0	
	Junction Temperature		t _j	125	°C
Storage Temperature Range			T _{stg}	-55~100	°C
Operating Temperature Range			T _{opr}	-20~85	°C
Lead Soldering Temperature (10s)			T _{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)			BV _S	2500	V _{rms}

Note 1: Device considered a two terminal device: pins 1, 2 and 3 shorted together, and pins 4, 5 and 8 shorted together.

Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MX.	UNIT
Supply Voltage	V_D	—	—	320	V
Forward Current	I_F	7.5	15	25	mA
On-State Current	I_{ON}	—	—	120	mA
Operating Temperature	T_{opr}	-20	—	80	°C

Circuit Connections

Individual Electrical Characteristics ($T_a = -25^{\circ}\text{C}$)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.*	MX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Off-State Current	I_{OFF}	$V_{OFF} = 400\text{V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1\text{MHz}$	—	—	—	pF

Coupled Electrical Characteristics ($T_a = 25^{\circ}\text{C}$)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Trigger LED Current		I_{FT}	$I_{ON} = 120\text{mA}$	—	1	5	mA
On-State Resistance	A Connection	R_{ON}	$I_{ON} = 120\text{mA}, I_F = 10\text{mA}$	—	20	30	Ω
	B Connection		$I_{ON} = 150\text{mA}, I_F = 10\text{mA}$	—	12	20	
	C Connection		$I_{ON} = 200\text{mA}, I_F = 10\text{mA}$	—	6	10	

Isolation Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Capacitance Input to Output	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	2500	—	—	V_{rms}
		AC, 1 second in oil	—	5000	—	
		DC, 1 minute in oil	—	5000	—	V_{dc}

Switching Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Turn-on Time	t_{on}	$R_L = 200\Omega$ $V_{\text{DD}} = 20\text{mA}, I_F = 10\text{mA}$	—	—	2	ms
Turn-off Time	t_{off}		—	—	2	

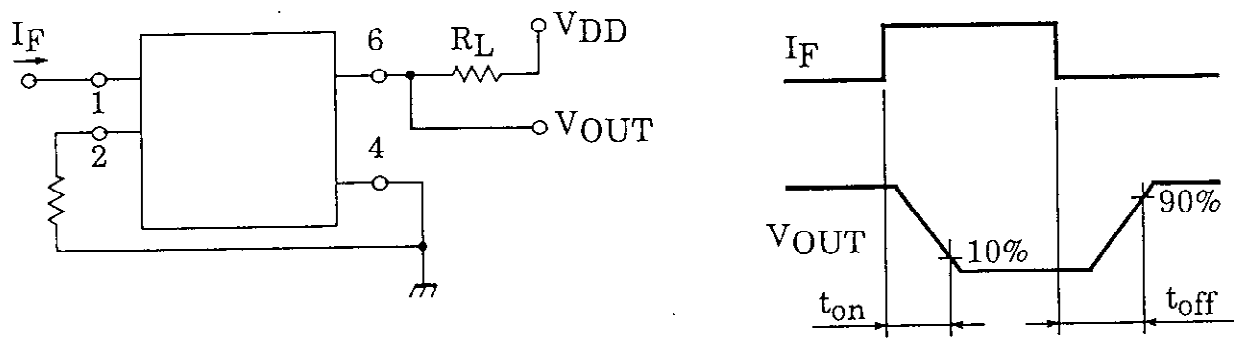


Figure 1. Switching Time Test Circuit

